

## Super Barrier Rectifier TM

Using state-of-the-art SBR IC process technology, the following features are made possible in a single device:

#### Major ratings and characteristics

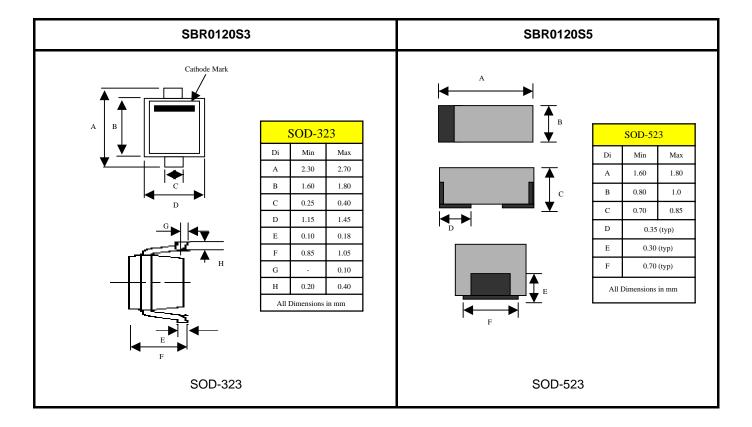
Characteristics	Values	Units
I <sub>F(AV)</sub> Rectangular Waveform	0.10	A
V <sub>RRM</sub>	20	V
V <sub>F</sub> @0.1A, T <sub>J</sub> =75°C	0.35	V, typ
T <sub>J</sub> (operating/storage)	-65 to 125	°C

#### ELECTRICAL:

- \* Low Forward Voltage Drop
- \* Low Reverse Leakage
- \* Reliable High Temperature Operation
- \* Super Barrier Design
- \* Softest, fast switching capability
- \* 125°C Operating Junction Temperature

### MECHANICAL:

\* Molded Plastic SOD-323, SOD-523 packages



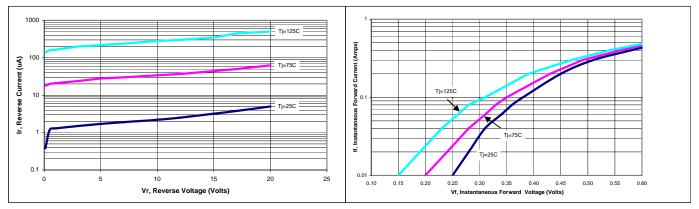
# APD Semiconductor, Inc.

<b>Maximum Ratings and Electrical Charac</b>	cteristics					
(at 25°C unless otherwise specified)						
	SYMBOL			UNITS		
DC Blocking Voltage Working Peak Reverse Voltage Peak Repetitive Reverse Voltage	V <sub>RM</sub> V <sub>RWM</sub> V <sub>RRM</sub>	20		Volts		
Average Rectified Forward Current (Rated V <sub>R</sub> -20Khz Square Wave)-50% duty cycle	I <sub>O</sub>	0.10		Amps		
Peak Forward Surge Current - 1/2 60hz	I <sub>FSM</sub>	2		Amps		
Instantaneous Forward Voltage I <sub>F</sub> = 100mA; T <sub>J</sub> = 25°C I <sub>F</sub> = 100mA; T <sub>J</sub> = 75°C	V <sub>F</sub>	Тур  	Max 0.41 0.38	Volts		
Maximum Reverse Current at Rated $V_{RM}$ T <sub>J</sub> = 25°C T <sub>J</sub> = 75°C	I <sub>R</sub> *	Тур 	Max 20 500	uA uA		
Operating and Storage Junction Temperature	TJ	-65 to +125		°C		

NOTE: Dice are available for customer applications.

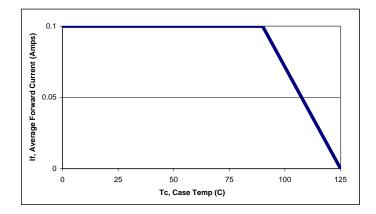
\* Pulse width < 300 uS, Duty cycle < 2%

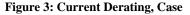




**Figure 1: Typical Reverse Current** 

**Figure 2: Typical Forward Voltage** 





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APD Semiconductor, Inc.

1 Lagoon Drive, Suite 410, Redwood City, CA 94065, USA Ph: 650 508 8896 FAX: 650 508 8865 Homepage: www.apdsemi.com email: info@apdsemi.com